

Polar™ Power MOSFET

IXTA12N50P IXTI12N50P IXTP12N50P

N-Channel Enhancement Mode Avalanche Rated

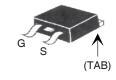


| Symbol | Test Conditions | | Maximum F | Ratings |
|---|--|------------------------------|-----------------------------|--------------------|
| V _{DSS} | $T_J = 25^{\circ}\text{C to } 150^{\circ}$ | С | 500 | V |
| V _{DGR} | $T_J = 25^{\circ}C \text{ to } 150^{\circ}$ | C, $R_{GS} = 1M\Omega$ | 500 | V |
| V _{GSS} | Continuous | | ±30 | V |
| V _{GSM} | Transient | | ±40 | V |
| I _{D25} | T _C = 25°C | | 12 | Α |
| I _{DM} | $T_{c} = 25^{\circ}C$, pulse v | width limited by $T_{_{JM}}$ | 30 | Α |
| I _A E _{AS} | T _C = 25°C T _C = 25°C | | 12 600 | A mJ |
| dV/dt | $I_{S} \leq I_{DM}, V_{DD} \leq V_{DS}$ | s, T _J ≤ 150°C | 10 | V/ns |
| $\overline{\mathbf{P}_{\scriptscriptstyle \mathrm{D}}}$ | T _C = 25°C | | 200 | W |
| T _J T _{JM} T _{stg} | | | -55 +150 150 -55 +150 | °C °C °C |
| T _L | 1.6mm (0.062) from | m case for 10s | 300 | °C |
| T _{SOLD} | Plastic body for 10 | S | 260 | °C |
| M _d M _d | Mounting torque Mounting force | (TO-220) (TO-263) | 1.13 / 10 1065 / 2.214.6 | Nm/lb.in. N/lb. |
| Weight | TO-263 Leaded TO-263 TO-220 | | 2.5 2.8 3.0 | g g |

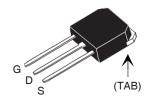
| Symbol Test Conditions (T _{.1} = 25°C, unless otherwise specified) | | | Cha Min. | Characteristic Values Min. Typ. Max. | | | |
|---|---|------------------------|-------------|---|----------|--------------------------|--|
| BV _{DSS} | $V_{GS} = 0V, I_{D} = 250\mu A$ | | 500 | | | | |
| V _{GS(th)} | $V_{DS} = V_{GS}, I_{D} = 250\mu A$ | | 3.0 | | 5.5 | V | |
| I _{GSS} | $V_{GS} = \pm 30V, V_{DS} = 0V$ | | | | ±100 | nA | |
| I _{DSS} | $V_{DS} = V_{DSS}$ $V_{GS} = 0V$ | T _J = 125°C | | | 5 250 | μ Α μ Α | |
| R _{DS(on)} | $V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note$ | te 1 | | | 500 | mΩ | |

 $V_{DSS} = 500V$ $I_{D25} = 12A$ $R_{DS(on)} \le 500m\Omega$

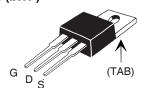
TO-263 (IXTA)



Leaded TO-263 (IXTI)



TO-220 (IXTP)



G = Gate D = DrainS = Source TAB = Drain

Features

- International standard packages
- Unclamped Inductive Switching (UIS) rated
- Low package inductance easy to drive and to protect

Advantages

- Easy to mount
- Space savings
- High power density



| • | | | Char Min. | Characteristic Values //in. Typ. Max. | | |
|--|---|---|--------------|--|-------------------|--|
| g _{fs} | | $V_{DS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$ | 7.5 | 13 | S | |
| C _{iss} C _{oss} C _{rss} | } | $V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$ | | 1830 182 16 | pF pF pF | |
| t _{d(on)} t _r t _{d(off)} | } | Resistive Switching Times $V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$ $R_{G} = 10\Omega$ (External) | | 22 27 65 20 | ns ns ns | |
| $\mathbf{Q}_{g(on)}$ \mathbf{Q}_{gs} \mathbf{Q}_{gd} | } | $V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D2S}$ | | 29 11 10 | nC nC nC | |
| R _{thJC} | | (TO-220) | | 0.50 | 0.62 °C/W °C/W | |

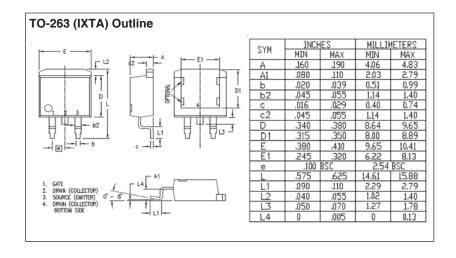
Source-Drain Diode

Characteristic Values

 $(T_J = 25^{\circ}C, \text{ unless otherwise specified})$

| Symbol | Test Conditions | Min. | Тур. | Max. |
|---|--|------|-------------|-------------------|
| I _s | $V_{GS} = 0V$ | | | 12 A |
| I _{SM} | Repetitive, pulse width limited by $T_{_{\rm JM}}$ | | | 48 A |
| $\mathbf{V}_{\mathtt{SD}}$ | $I_F = I_S$, $V_{GS} = 0V$, Note 1 | | | 1.5 V |
| t _{rr} Q _{RM} I _{RM} | $\begin{cases} I_{_{F}} = 6A, -di/dt = 150A/\mu s, \\ V_{_{R}} = 100V, V_{_{GS}} = 0V \end{cases}$ | | 2.8 18.2 | 300 ns μC A |

Note 1: Pulse test, $t \le 300 \mu s$; duty cycle, $d \le 2\%$.

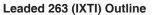


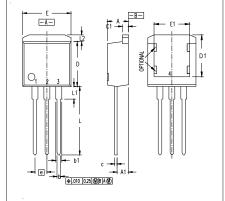
TO-220 (IXTP) Outline

Pins: 1 - Gate

2 - Drain

| MYZ | INCHES | | MILLIMETERS | |
|------|----------|------|-------------|-------|
| 2114 | MIN | MAX | MIN | MAX |
| Α | .170 | .190 | 4.32 | 4.83 |
| b | .025 | .040 | 0.64 | 1.02 |
| b1 | .045 | .065 | 1.15 | 1.65 |
| С | .014 | .022 | 0.35 | 0.56 |
| D | .580 | .630 | 14.73 | 16.00 |
| E | .390 | .420 | 9.91 | 10.66 |
| е | .100 BSC | | 2.54 BSC | |
| F | .045 | .055 | 1.14 | 1.40 |
| H1 | .230 | .270 | 5.85 | 6.85 |
| J1 | .090 | .110 | 2.29 | 2.79 |
| k | 0 | .015 | 0 | 0.38 |
| L | .500 | .550 | 12.70 | 13.97 |
| L1 | .110 | .230 | 2.79 | 5.84 |
| ØΡ | .139 | .161 | 3.53 | 4.08 |
| Q | .100 | .125 | 2.54 | 3.18 |





| MY2 | INCHES | | MILLIMETERS | | |
|-------|--------|------|-------------|-------|--|
| 2 I M | MIN | MAX | MIN | MAX | |
| Α | .160 | .190 | 4.06 | 4.83 | |
| A1 | .080 | .110 | 2.03 | 2.79 | |
| b | .025 | .039 | 0.51 | 0.99 | |
| b2 | .025 | .039 | 1.14 | 1.40 | |
| С | .018 | .029 | 0.46 | 0.74 | |
| c2 | .018 | .029 | 1.14 | 1.40 | |
| D | .340 | .380 | 8.64 | 9.65 | |
| D1 | .315 | .350 | 8.00 | 8.89 | |
| E | .380 | .405 | 9.65 | 10.29 | |
| E1 | .245 | .320 | 6.22 | 8.13 | |
| е | .100 | BSC | 2.54 | BSC | |
| L | .500 | .580 | 14.61 | 15.88 | |
| L1 | .080 | .130 | 2.29 | 2.79 | |
| 12 | 040 | 055 | 102 | 1.40 | |

NOTE: This drawing will meet all dimensions requirement of JEDEC outline TO-262 AA.

IXYS reserves the right to change limits, test conditions, and dimensions.



Fig. 1. Output Characteristics
@ 25°C

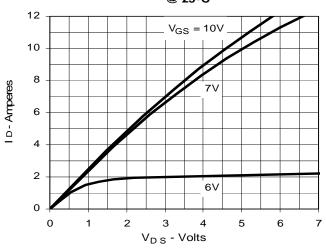


Fig. 3. Output Characteristics
@ 125°C

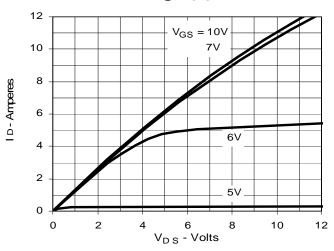


Fig. 5. R_{DS(on)} Normalized to I_D = 6A Value vs. Drain Current

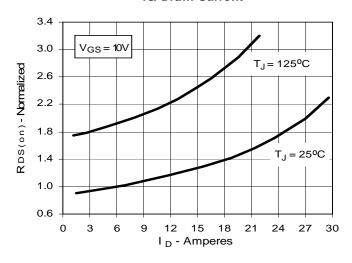


Fig. 2. Extended Output Characteristics
@ 25°C

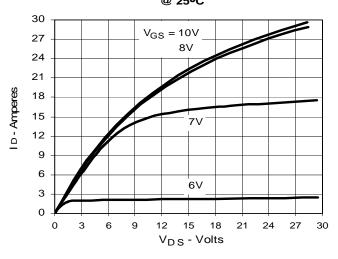


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 6A$ Value vs. Junction Temperature

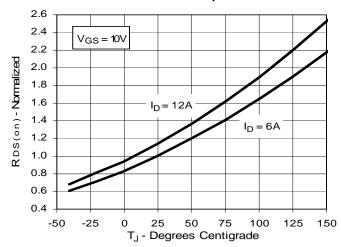
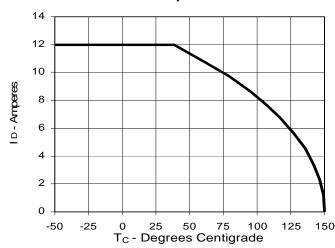


Fig. 6. Drain Current vs. Case Temperature



I D - Amperes

2

0

4.5

5.0

5.5

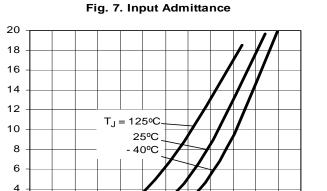


Fig. 9. Source Current vs. Source-To-Drain Voltage

6.0

 $V_{G\ S}$ - Volts

6.5

7.0

7.5

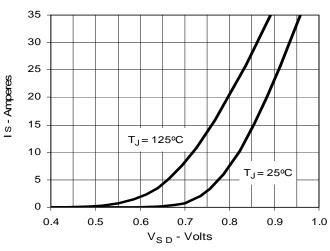


Fig. 11. Capacitance

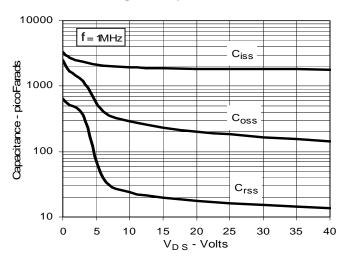


Fig. 8. Transconductance

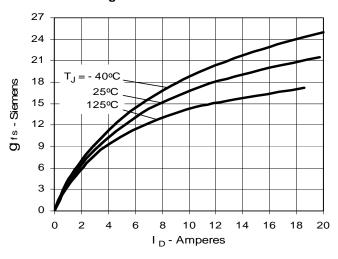


Fig. 10. Gate Charge

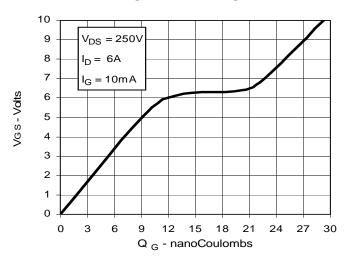
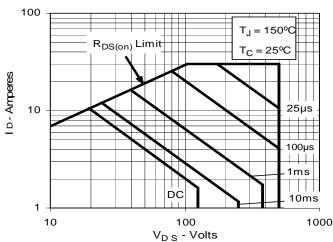


Fig. 12. Forward-Bias Safe Operating Area



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Fig. 13. Maximum Transient Thermal Impedance